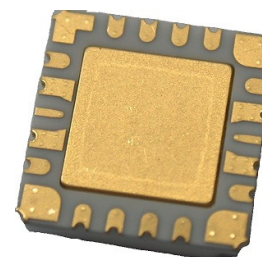


## 27 – 29.5 GHz 2W PA MMIC(Package Form)

### FEATURES

- Psat : +33.0dBm
- P1dB : +32.5dBm
- IMD3 : +41.0dBc @ Pscl +20dBm
- Small Signal Gain: 13.0dB
- Bias Condition: 1800mA @ +6V



### APPLICATIONS

- New 5G Radio Link
- VSAT
- Sat-Com
- Point-to-Point Radio

### DESCRIPTION

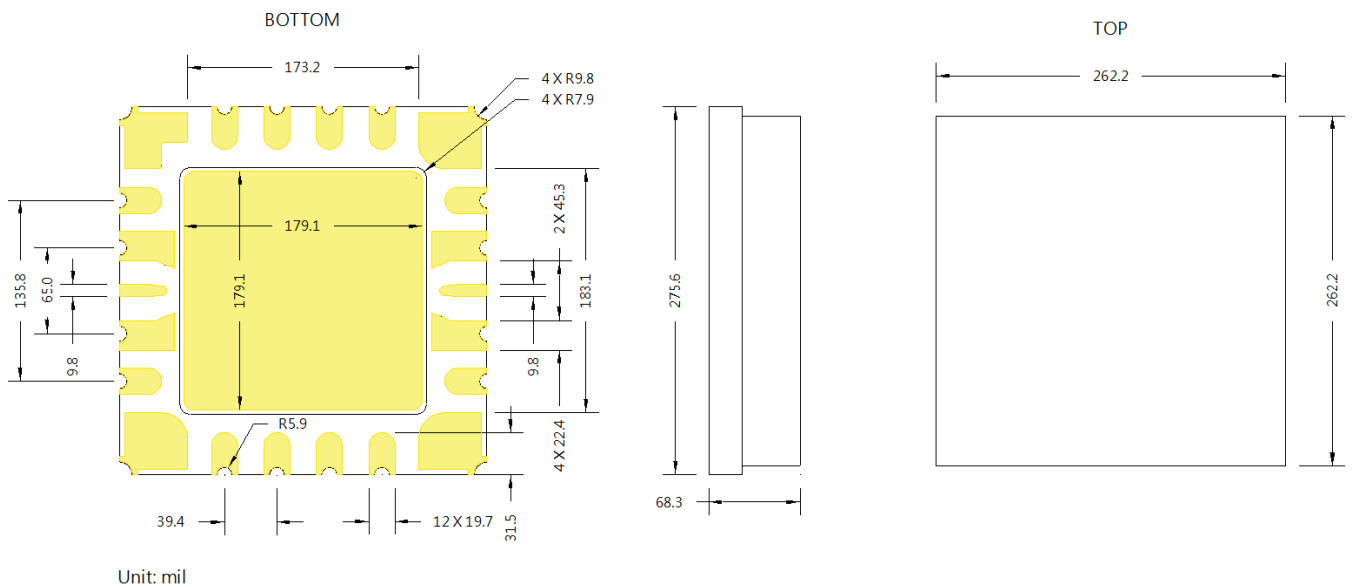
The TC5285P is a two-stages PHEMT high power amplifier package form MMIC that operates from 27 to 29.5 GHz. The amplifier provides a typical 13 dB of gain and delivers +33 dBm of Pout. The MMIC is fabricated using Transcom's proprietary matured GaAs PHEMT process. The process features full passivation for increased performance and reliability. All devices are 100 % DC tested to assure consistent quality. Bond pads are gold plated for either thermocompression or thermosonic wire bonding. Backside gold plating is compatible with standard AuSn die-attach.

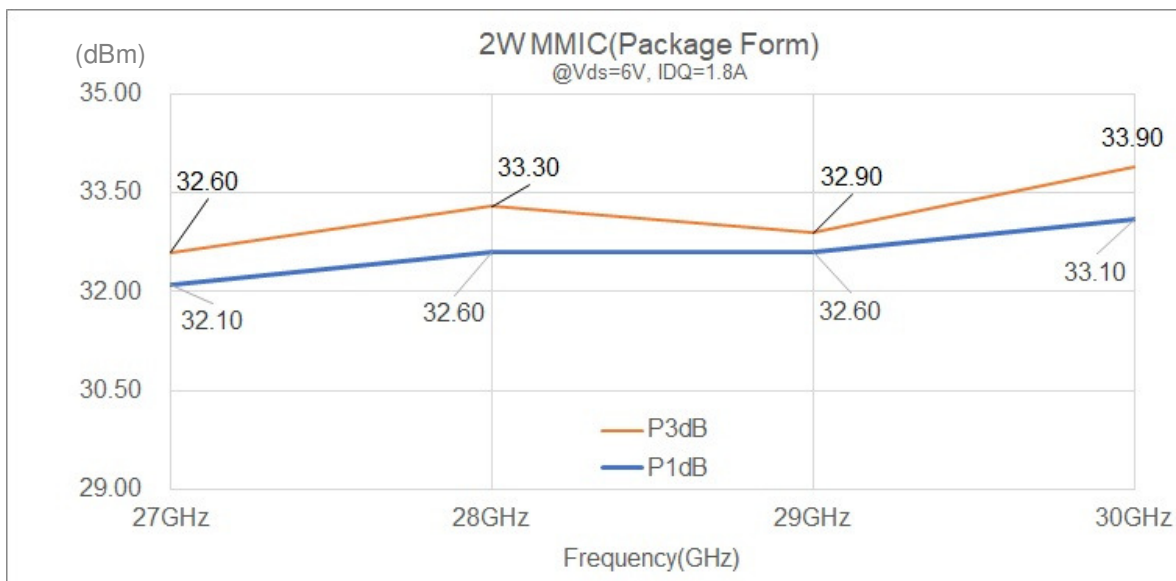
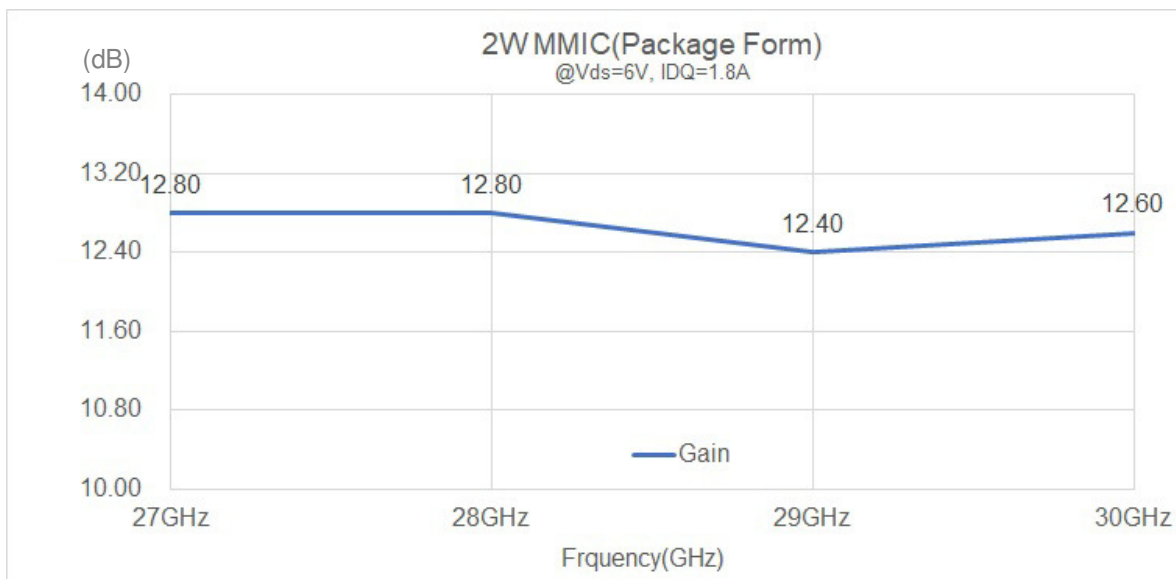
### ELECTRICAL SPECIFICATIONS (Ta = 25 °C)

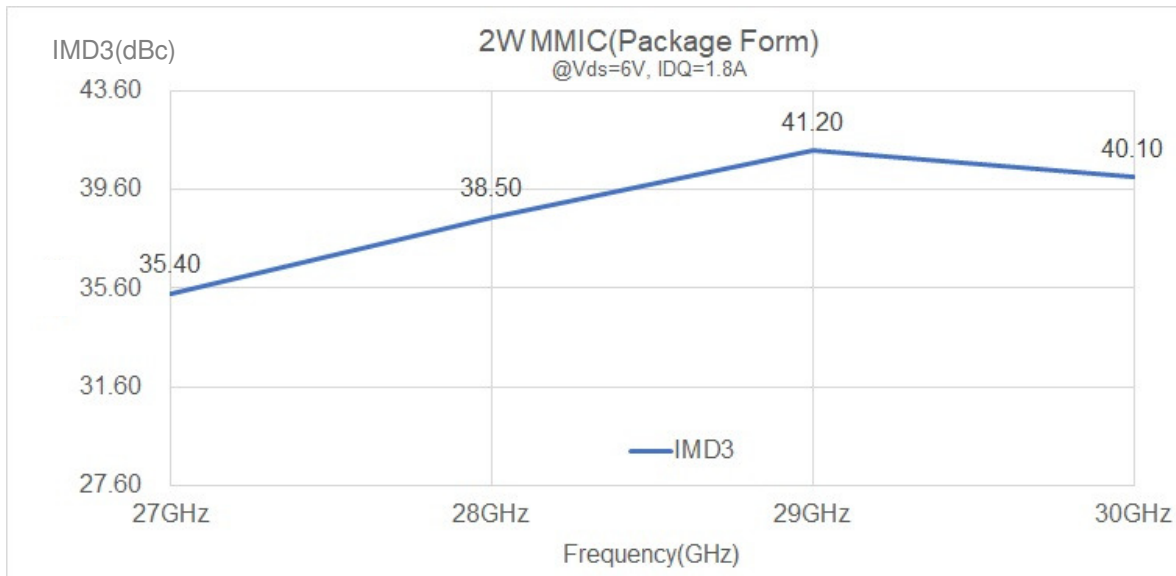
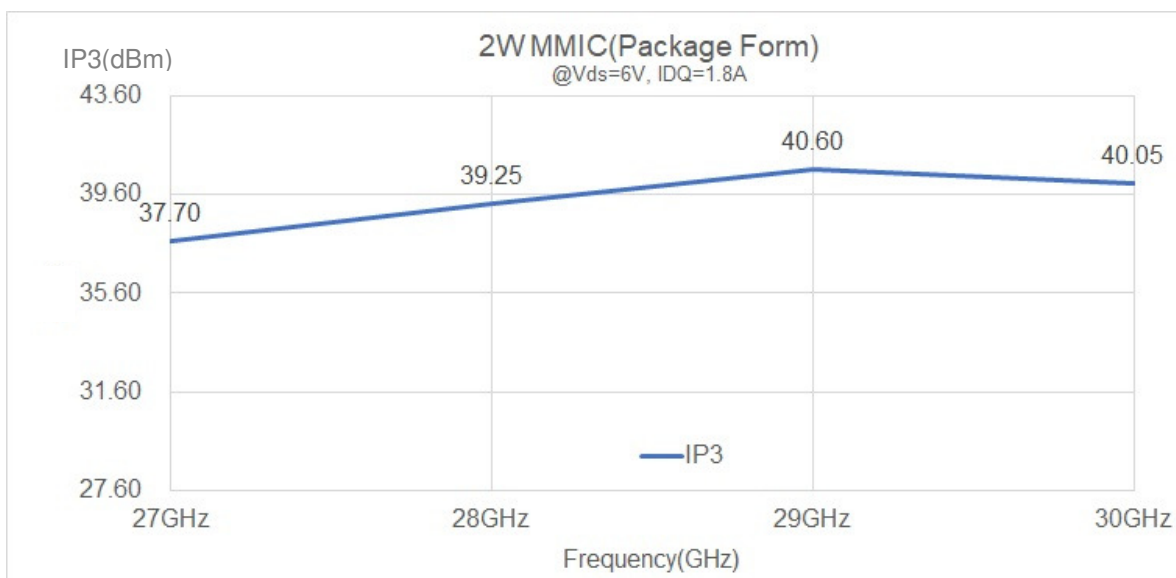
SYMBOL	DESCRIPTION	MIN	TYP	MAX	UNITS
<b>FREQ</b>	Frequency Range	27		29.5	GHz
<b>SSG</b>	Small Signal Gain		13		dB
<b>Psat</b>	Saturation Output Power		33.0		dBm
<b>P1dB</b>	1dB Compression Output Power		32.5		dBm
<b>IMD3</b>	The Third Intermodulation level at Pout +20dBm/tone, $\Delta f=1\text{MHz}$		41.0		dBc
<b>I.L., IN</b>	Input Return Loss		8		dB
<b>I.L., OUT</b>	Output Return Loss		10		dB
<b>VDD</b>	Supply Voltage		+6		Volt
<b>IDQ</b>	Current Supply Without RF		1,800		mA
<b>IDRF</b>	Current Supply @ Pout		2,150		mA

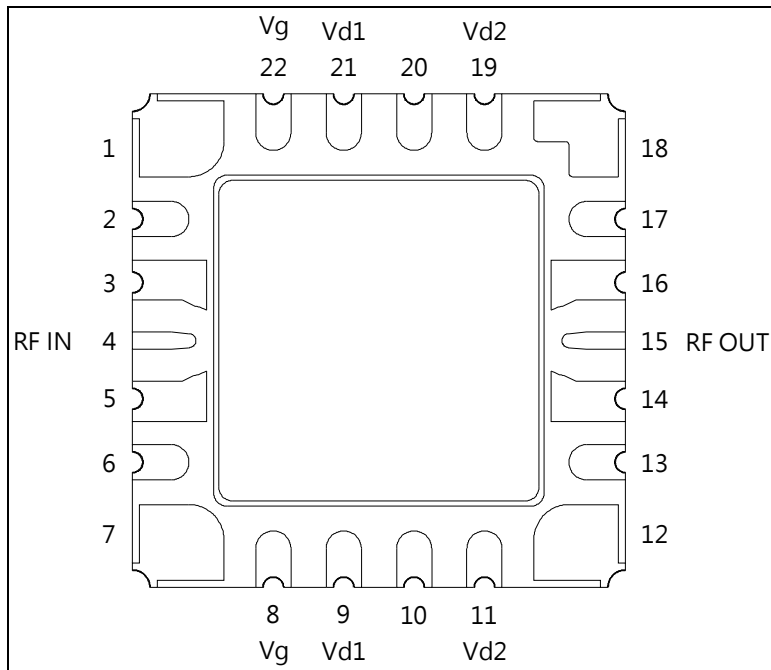
**ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Rating
$V_{DS}$	Drain-Source Voltage	7.0 V
$I_D$	Drain Current	2.5 A
$P_T$	Continuous Dissipation	18 W
$P_{in}$	Input Power, CW	+25 dBm
Tch	Channel Temperature	+175
$T_{STG}$	Storage Temperature	- 50 °C to +150 °C

**PHYSICAL DIMENSIONS (unit : mil)**


**TYPICAL CHARACTERISTICS**
Pout vs Freq.

Gain vs Freq.


**IMD3 vs Freq (@P<sub>scl</sub> = +20dBm)**

**IP3 vs Freq**


**CONNECTION DIAGRAM AND PIN DESCRIPTIONS**

**PIN ASSIGNMENT**

Pin No.	Symbol	Description
1-3, 5-7, 10, 12-14, 16-18, 20	GND	Ground.
4	RF IN	RF Input, matched to 50 $\Omega$ .
8、22	Vg	Negative Gate voltage, connected to either pin 8 or pin 22.
9、21	Vd1	Positive Drain voltage, connected to either pin 9 or pin 21.
11、19	Vd2	Positive Drain voltage, connected to either pin 11 or pin 19.
15	RF OUT	RF Output, matched to 50 $\Omega$ .